Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN0606-3 (SOT8001) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection up to 1.8 kV HBM
- Leadless ultra small and ultra thin SMD plastic package: 0.62 × 0.62 × 0.37 mm

3. Applications

- Relay driver
- High-speed line driver
- · High-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-0.8	А
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -0.6 \text{ A}; T_j = 25 \text{ °C}$		-	550	640	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	Transparent top view DFN0606-3 (SOT8001)	G S 017aaa259

6. Ordering information

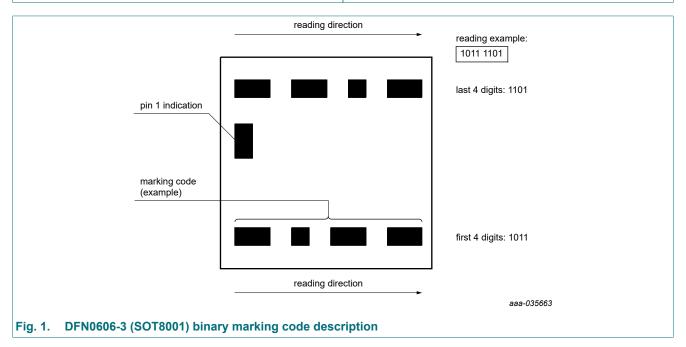
Table 3. Ordering information

· · · · · · · · · · · · · · · · · · ·						
Type number	Package					
	Name	Description	Version			
PMH550UPE		plastic, leadless ultra small package; 3 terminals; body 0.62 x 0.62 x 0.37 mm	SOT8001			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMH550UPE	0001 1000



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V_{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-0.8	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-0.5	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-2	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	0.36	W
			[1]	-	0.66	W
		T _{sp} = 25 °C		-	2.23	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	n diode		'	1		
Is	source current	T _{amb} = 25 °C	[1]	-	-0.6	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

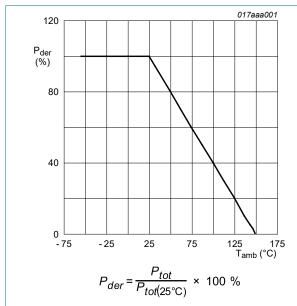


Fig. 2. Normalized total power dissipation as a function of ambient temperature

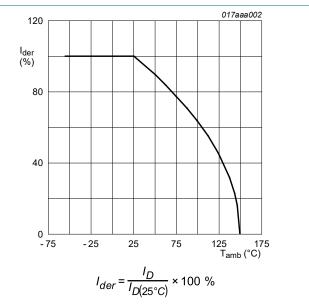


Fig. 3. Normalized continuous drain current as a function of ambient temperature

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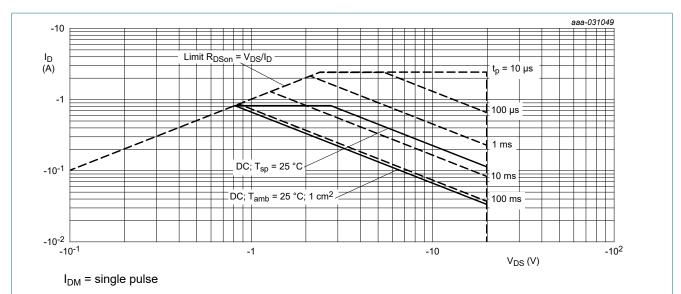


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	287	344	K/W
	junction to ambient		[2]	-	158	190	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	47	56	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².

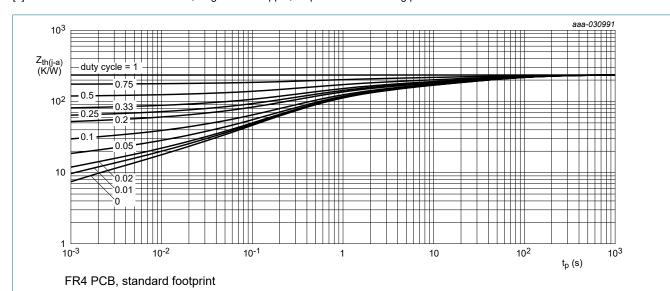


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

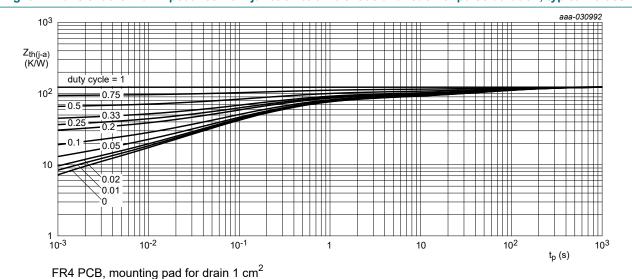


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V_{GSth}	gate-source threshold voltage	I_D = -250 μ A; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μΑ
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	-20	μΑ
I _{GSS}	gate leakage current	V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-5	μΑ
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	5	μΑ
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μΑ
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{GS} = -2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
Doon	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -0.6 \text{ A}; T_j = 25 \text{ °C}$	-	550	640	mΩ
	resistance	$V_{GS} = -4.5 \text{ V}; I_D = -0.6 \text{ A}; T_j = 150 \text{ °C}$	-	850	990	mΩ
		$V_{GS} = -2.5 \text{ V}; I_D = -0.3 \text{ A}; T_j = 25 \text{ °C}$	-	788	930	mΩ
		$V_{GS} = -1.8 \text{ V}; I_D = -0.08 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	1.17	1.9	Ω
9 _{fs}	forward transconductance	$V_{DS} = -10 \text{ V}; I_D = -0.6 \text{ A}; T_j = 25 \text{ °C}$	-	1.1	-	S
R _G	gate resistance	f = 1 MHz	-	19.2	-	Ω
Dynamic ch	naracteristics				<u>'</u>	
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I_D = -0.6 A; V_{GS} = -4.5 V;	-	0.6	0.9	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.1	-	nC
Q_{GD}	gate-drain charge		-	0.16	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	54.8	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	11.2	-	pF
C _{rss}	reverse transfer capacitance		-	7.7	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -0.6 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	2	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	2	-	ns
t _{d(off)}	turn-off delay time		-	5	-	ns
t _f	fall time		-	3	-	ns
Source-dra	in diode		'			
V _{SD}	source-drain voltage	$I_S = -0.6 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V

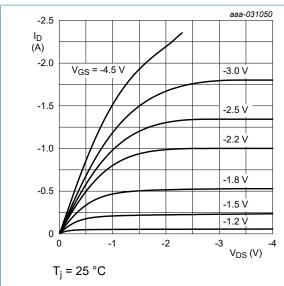


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

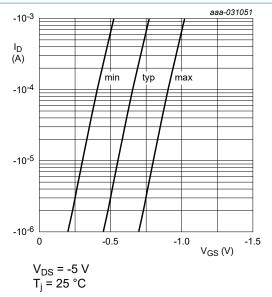


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

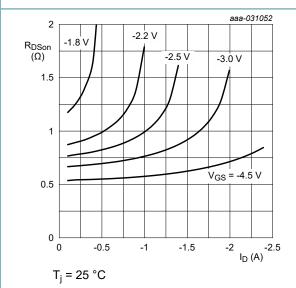


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

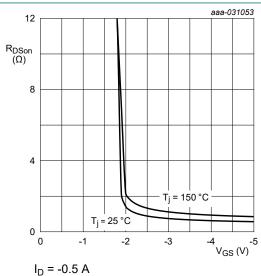


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

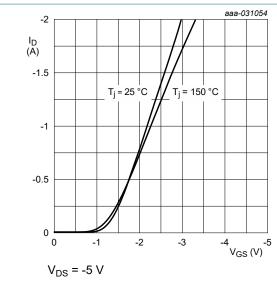


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

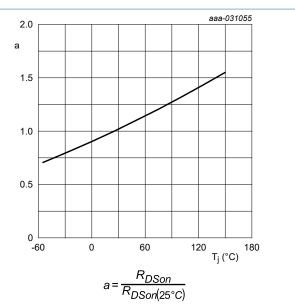


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

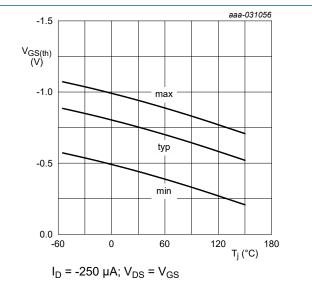


Fig. 13. Gate-source threshold voltage as a function of junction temperature

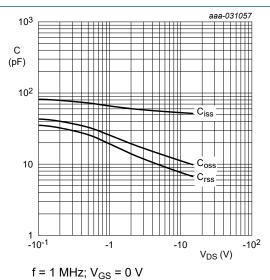


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical

values

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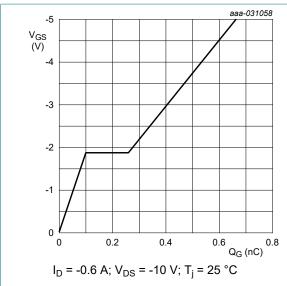


Fig. 15. Gate-source voltage as a function of gate charge; typical values

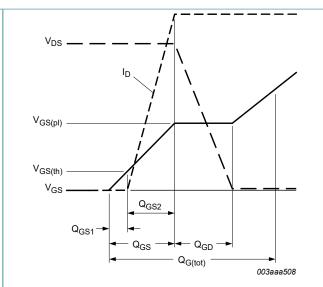


Fig. 16. Gate charge waveform definitions

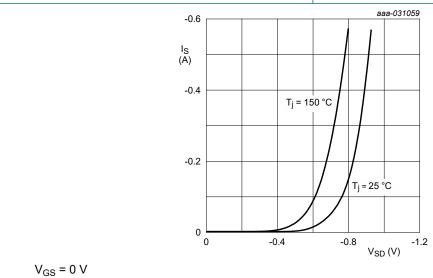
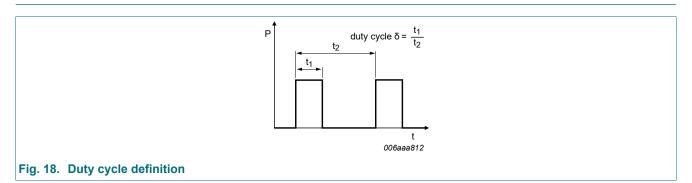


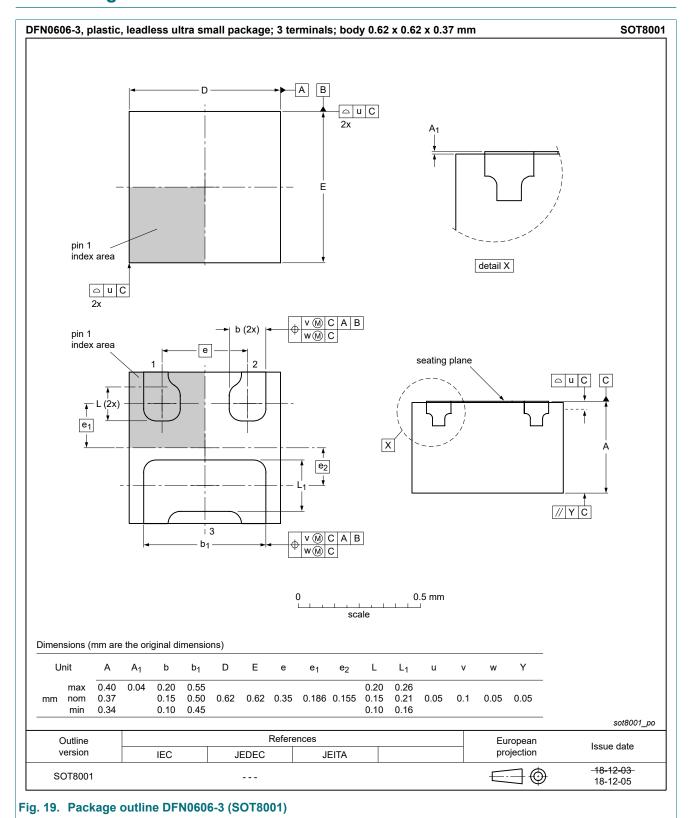
Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information



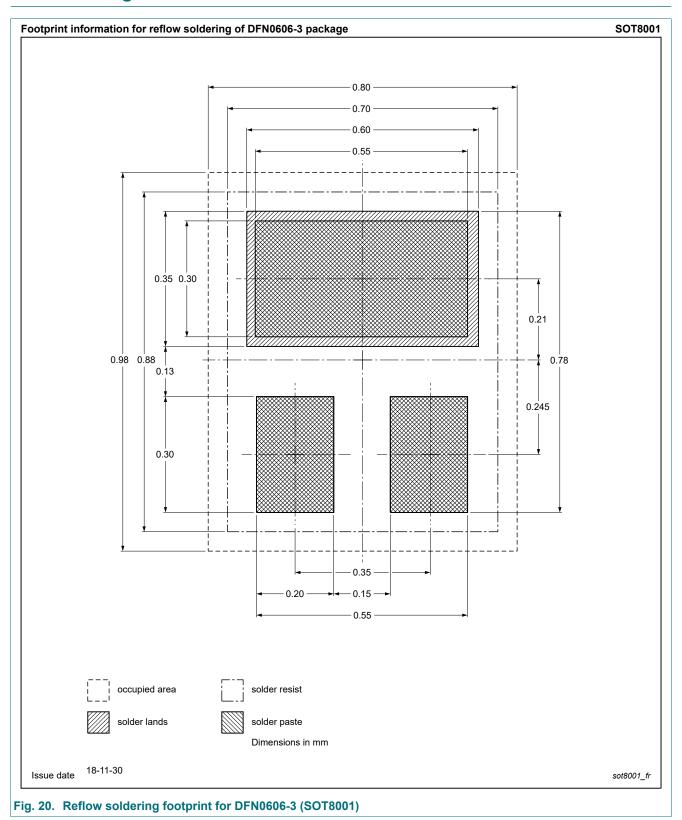
PMH550UPE

12. Package outline



PMH550UPE

13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMH550UPE v.2	20230206	Product data sheet	-	PMH550UPE v.1		
Modifications:	Fig. 1, clarifying the reading example					
PMH550UPE v.1	20200408	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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